



1.1MHz, Precision, Rail-to-Rail I/O CMOS Operational Amplifier

FEATURES

- HIGH GAIN BANDWIDTH:1.1MHz
- RAIL-TO-RAIL INPUT AND OUTPUT 0.5mV Max Vos
- INPUT VOLTAGE RANGE: -0.2V to +5.7V with Vs = 5.5V
- SUPPLY RANGE: +2.1V to +5.5V
- SPECIFIED UP TO +125°C
- Micro SIZE PACKAGES: SOT23-5, SC70-5

APPLICATIONS

- SENSORS
- PHOTODIODE AMPLIFICATION
- ACTIVE FILTERS
- TEST EQUIPMENT
- DRIVING A/D CONVERTERS

DESCRIPTIONS

The RS321P, RS321BP families of products offer low voltage operation and rail-to-rail input and output, as well as excellent speed/power consumption ratio, providing an excellent bandwidth (1.1MHz) and slew rate of 0.5V/us. The op-amps are unity gain stable and feature an ultra-low input bias current.

The RS321P, RS321BP has lower offset, which is guaranteed not upper than 0.5mV at 25°C with $V_S=5V$, $V_{CM}=V_S/2$.

The devices are ideal for sensor interfaces, active filters and portable applications. The RS321P, RS321BP families of operational amplifiers are specified at the full temperature range of -40°C to +125°C under single supplies of 2.1V to 5.5V or dual power supplies of ±1.05V to ±2.75V.

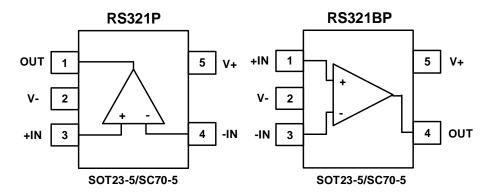
Device Information (1)

PART NUMBER	NUMBER PACKAGE BODY SIZE(NO	
RS321P/RS321BP	SOT23-5	2.90mm × 1.60mm
K3321F/K3321BF	SC70-5	2.10mm × 1.25mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.



Pin Configuration and Functions (Top View)



Pin Description

	PIN			
NAME	RS321P	RS321BP	I/O	DESCRIPTION
	SOT23-5/SC70-5	SOT23-5/SC70-5		
-IN	4	3	I	Negative (inverting) input
+IN	3	1	I	Positive (noninverting) input
NC	-	-	-	No internal connection (can be left floating)
OUT	1	4	0	Output
V-	2	2	-	Negative (lowest) power supply
V+	5	5	-	Positive (highest) power supply



SPECIFICATIONS

Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted) (1)

		MIN	MAX	UNIT
	Supply, V _S =(V+) - (V-)		7	
Voltage	Signal input pin (2)	(V-)-0.5	(V+) +0.5	V
	Signal output pin (3)	(V-)-0.5	(V+) +0.5	
	Signal input pin (2)	-10	10	mA
Current	Signal output pin (3)	-140	140	mA
	Output short-circuit (4)	Con	tinuous	
	Operating range, T _A	-40	125	
Temperature	Junction, T _J		150	°C
	Storage, T _{stg}	-65	150	

- (1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.
- (2) Input terminals are diode-clamped to the power-supply rails. Input signals that can swing more than 0.5V beyond the supply rails should be current-limited to 10mA or less.
- (3) Output terminals are diode-clamped to the power-supply rails. Output signals that can swing more than 0.5V beyond the supply rails should be current-limited to $\pm 100 mA$ or less.
- (4) Short-circuit to ground, one amplifier per package.

ESD Ratings

			VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human-body model (HBM)	3000	\/
V (ESD)	Liectrostatic discriarge	Machine Model (MM)	200	V

Recommended Operating Conditions

Over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT	
Supply voltage V- (V)	Single-supply	2.1		5.5	.,	
Supply voltage, V _S = (V+) - (V-)	Dual-supply	±1.05		±2.75	V	
Specified temperature		-40		125	°C	

Thermal Information: RS321P/RS321BP

THERMAL METRIC (1)			RS321P/RS321BP 5PINS		
		SOT23-5	SC70-5	UNIT	
R _{OJA}	Junction-to-ambient thermal resistance	273.8	214.7	°C/W	
R _{OJC(top)}	Junction-to-case(top) thermal resistance	126.8	127.1	°C/W	
R _{OJB}	Junction-to-board thermal resistance	85.9	60.0	°C/W	
Ψ_{JT}	Junction-to-top characterization parameter	10.9	33.4	°C/W	
Ψ_{JB}	Junction-to-board characterization parameter	84.9	59.8	°C/W	
R _{OJC(bot)}	Junction-to-case(bottom) thermal resistance	N/A	N/A	°C/W	



PACKAGE/ORDERING INFORMATION

Orderable Device	Package Type	Pin	Channel	Op Temp(°C)	Device Marking	Package Qty
RS321PXF	SOT23-5	5	1	-40°C ~125°C	321P	Tape and Reel,3000
RS321PXC5	SC70-5 (1)	5	1	-40°C ~125°C	321P	Tape and Reel,3000
RS321BPXF	SOT23-5	5	1	-40°C ~125°C	321BP	Tape and Reel,3000
RS321BPXC5	SC70-5 (1)	5	1	-40°C ~125°C	321BP	Tape and Reel,3000

NOTE: (1) Equivalent to SOT353.



ELECTRICAL CHARACTERISTICS

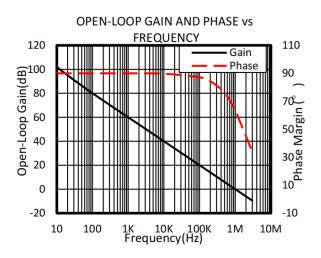
(At $T_A = +25^{\circ}C$, $V_S=5V$, $R_L = 10k\Omega$ connected to $V_S/2$, and $V_{OUT} = V_S/2$, unless otherwise noted.)

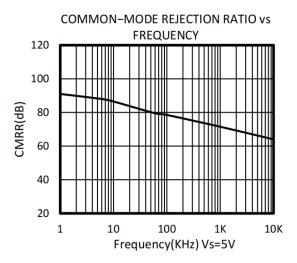
	DADAMETED	CONDITIONS	-	RS321P/RS321BP			
	PARAMETER	CONDITIONS	T₃	MIN	TYP	MAX	UNITS
POWE	R SUPPLY						
Vs	Operating Voltage Range		25°C	2.1		5.5	V
IQ	Quiescent Current		25°C		85	150	uA
PSRR	Dower Supply Bejection Botio	Vs=2.1V to 5.5V,	25°C	72	90		-10
FORK	Power-Supply Rejection Ratio	V _{CM} =(V-)+0.5V	-40°C to125°C	64			dB
ton	Turn-on time	Vs= 5V			25		us
INPUT							
Vos	Input Offset Voltage	RS321P/RS321BP	25°C	-0.5	±0.2	0.5	mV
VosTc	Input Offset Voltage Average Drift	-40°C to125°C	-40°C to125°C		2		uV/°C
IB	Input Bias Current		25°C		1	10	pА
los	Input Offset Current		25°C		1	10	pА
Vcm	Common-Mode Voltage Range	V _S = 5.5V	25°C	-0.2		5.7	V
	Common-Mode Rejection Ratio	V _S = 5.5V, V _{CM} =-0.2V to 4V	25°C	71	92		- dB
CMRR			-40°C to125°C	65			
		Vs= 5.5V, V _{CM} =-0.2V to 5.7V	25°C	61	83		
			-40°C to125°C	57			
OUTPL	JT						
		R _L =2KΩ,Vo= 0.15V to 4.85V	25°C	93	105		- dB
AOL	Onen Leen Veltage Cain		-40°C to125°C	83			
AOL	Open-Loop Voltage Gain	R _L =10KΩ, Vo=	25°C	100	110		
		0.05V to 4.95V	-40°C to125°C	92			
	Output Swing from Bail	R _L =2KΩ	2500		25		mV
	Output Swing from Rail	R _L =10KΩ	25°C		8		IIIV
lout	Output Short-Circuit Current		25°C		110		mA
FREQU	JENCY RESPONSE						
SR	Slew Rate	C _L =100pF, G=1	25°C		0.5		V/us
GBP	Gain-Bandwidth Product		25°C		1.1		MHz
PM	Phase Margin		25°C		64		0
ts	Setting Time,0.1%	C _L =100pF,Vs=5V, 2-V step, G=1			6.5		us
	Overload Recovery Time	V _{IN} -Gain≥V _S			4		us
NOISE							
_	Input Voltage Naiss Density	f = 1KHz	25°C		22		nV/√Hz
e n	Input Voltage Noise Density	f = 10KHz	25°C		20		nV/√Hz

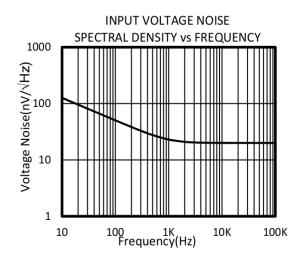


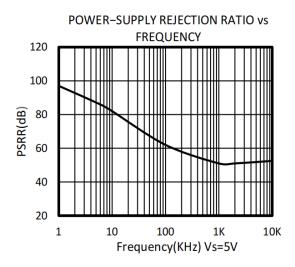
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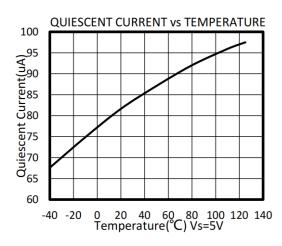
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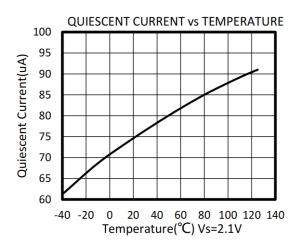








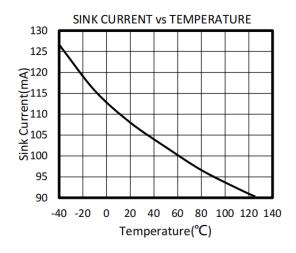


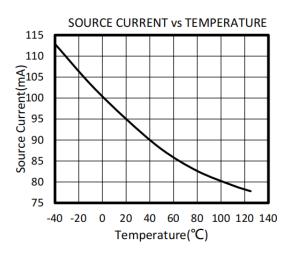


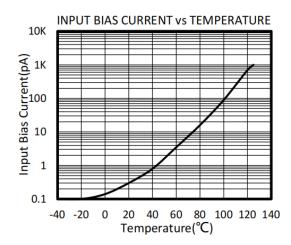


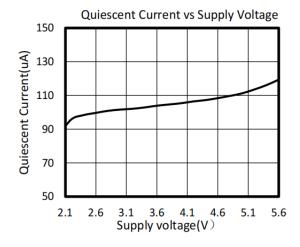
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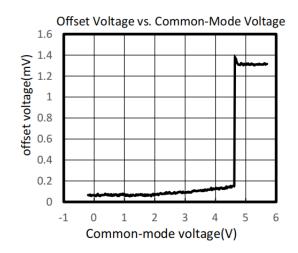
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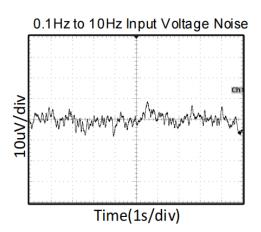








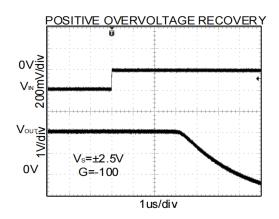


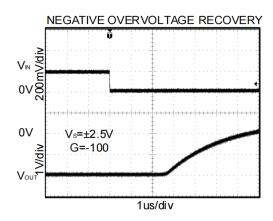


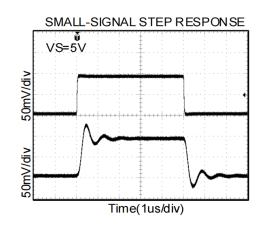


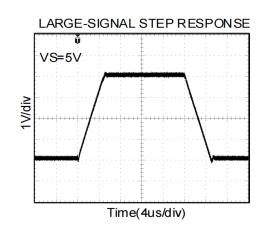
TYPICAL CHARACTERISTICS

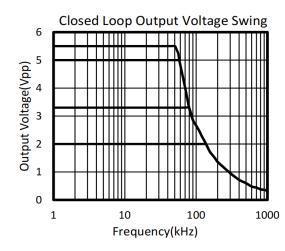
At $T_A = +25$ °C, $V_S=5V$, $R_L = 10k\Omega$ connected to $V_S/2$, $V_{OUT} = V_S/2$, unless otherwise noted.

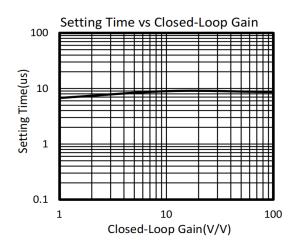














Detailed Description

Overview

The RS321P, RS321BP devices are unity-gain stable, single-channel op amps with low noise and distortion. The device consists of a low noise input stage with a folded cascade and a rail-to-rail output stage. This topology exhibits superior noise and distortion performance across a wide range of supply voltages that are not delivered by legacy commodity audio operational amplifiers.

Phase Reversal Protection

The RS321P, RS321BP family has internal phase-reversal protection. Many op amps exhibit phase reversal when the input is driven beyond the linear common-mode range. This condition is most often encountered in noninverting circuits when the input is driven beyond the specified common-mode voltage range, causing the output to reverse into the opposite rail. The input of the RS321P, RS321BP prevents phase reversal with excessive common-mode voltage. Instead, the appropriate rail limits the output voltage. This performance is shown in figure 1.

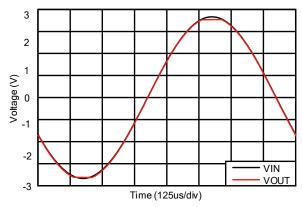


Figure 1. Output Waveform Devoid of Phase Reversal During an Input Overdrive Condition

EMI Rejection Ratio (EMIRR)

The electromagnetic interference (EMI) rejection ratio, or EMIRR, describes the EMI immunity of operational amplifiers. An adverse effect that is common to many operational amplifiers is a change in the offset voltage as a result of RF signal rectification. An operational amplifier that is more efficient at rejecting this change in offset as a result of EMI has a higher EMIRR and is quantified by a decibel value. Measuring EMIRR can be performed in many ways, but this document provides the EMIRR IN+, which specifically describes the EMIRR performance when the RF signal is applied to the noninverting input pin of the operational amplifier. In general, only the noninverting input is tested for EMIRR for the following three reasons:

- Operational amplifier input pins are known to be the most sensitive to EMI, and typically rectify RF signals better than the supply or output pins.
- The noninverting and inverting operational amplifier inputs have symmetrical physical layouts and exhibit nearly matching EMIRR performance.
- EMIRR is easier to measure on noninverting pins than on other pins because the noninverting input pin can be isolated on a printed-circuit-board (PCB). This isolation allows the RF signal to be applied directly to the noninverting input pin with no complex interactions from other components or connecting PCB traces.



Detailed Description (continued)

The EMIRR IN+ of the RS321P, RS321BP is plotted versus frequency in Figure 2. If available, any dual and quad operational amplifier device versions have approximately identical EMIRR IN+ performance. The RS321P, RS321BP unity-gain bandwidth is 1.1MHz. EMIRR performance below this frequency denotes interfering signals that fall within the operational amplifier bandwidth.

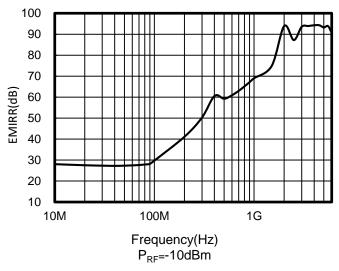


Figure 2.RS321P/RS321BP EMIRR vs Frequency

EMIRR IN+ Test Configuration

Figure 3 shows the circuit configuration for testing the EMIRR IN+. An RF source is connected to the operational amplifier noninverting input pin using a transmission line. The operational amplifier is configured in a unity-gain buffer topology with the output connected to a low-pass filter (LPF) and a digital multimeter (DMM). A large impedance mismatch at the operational amplifier input causes a voltage reflection; however, this effect is characterized and accounted for when determining the EMIRR IN+. The resulting dc offset voltage is sampled and measured by the multimeter. The LPF isolates the multimeter from residual RF signals that can interfere with multimeter accuracy.

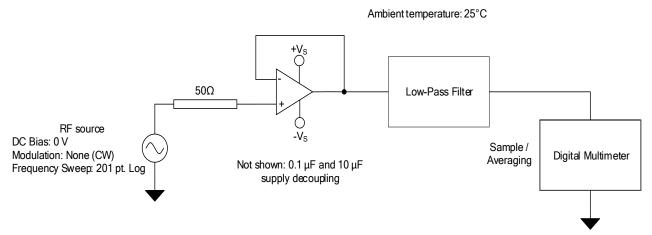


Figure 3. EMIRR IN+ Test Configuration Schematic



APPLICATION NOTE

The RS321P, RS321BP are high precision, rail-to-rail operational amplifiers that can be run from a single-supply voltage 2.1V to 5.5V (±1.05V to ±2.75V). Supply voltages higher than 7V (absolute maximum) can permanently damage the amplifier. Rail-to-rail input and output swing significantly increases dynamic range, especially in low-supply applications. Good layout practice mandates use of a 0.1uF capacitor place closely across the supply pins.

Typical Applications 25-kHz Low-pass Filter

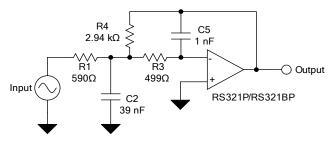


Figure 4. 25-kHz Low-Pass Filter

Design Requirements

Low-pass filters are commonly employed in signal processing applications to reduce noise and prevent aliasing. The RS321P, RS321BP devices are ideally suited to construct high-speed, high-precision active filters. Figure 11 shows a second-order, low-pass filter commonly encountered in signal processing applications.

Use the following parameters for this design example:

- Gain = 5 V/V (inverting gain)
- Low-pass cutoff frequency = 25 kHz
- Second-order Chebyshev filter response with 3-dB gain peaking in the passband

Detailed Design Procedure

The infinite-gain multiple-feedback circuit for a low-pass network function is shown in Figure 11. Use Equation 1 to calculate the voltage transfer function.

$$\frac{\text{Output}}{\text{Input}}(s) = \frac{-1/R_1 R_3 C_2 C_5}{s^2 + (s/C_2) (1/R_1 + 1/R_3 + 1/R_4) + 1/R_3 R_4 C_2 C_5}$$
(1)

This circuit produces a signal inversion. For this circuit, the gain at dc and the low-pass cutoff frequency are calculated by Equation 2:

Gain =
$$\frac{R_4}{R_1}$$

 $f_C = \frac{1}{2\pi} \sqrt{(\sqrt{R_3 R_4 C_2 C_5})}$ (2)

Application Curve

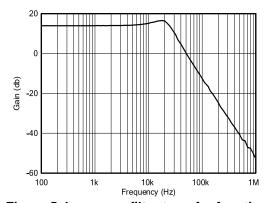
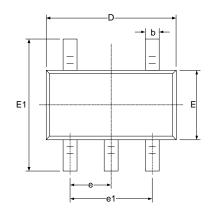
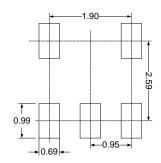


Figure 5. Low-pass filter transfer function

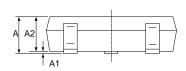


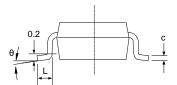
PACKAGE OUTLINE DIMENSIONS SOT23-5





RECOMMENDED LAND PATTERN (Unit: mm)

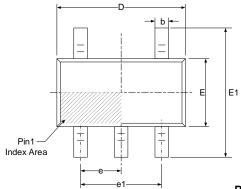


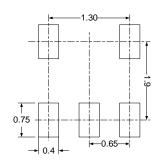


Symbol	Dimensions I	n Millimeters	Dimension	s In Inches
Symbol	Min	Max	Min	Max
А	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
е	0.950	0.950(BSC)		(BSC)
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

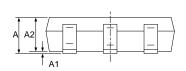


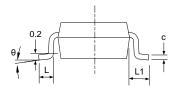
SC70-5





RECOMMENDED LAND PATTERN (Unit: mm)





Sumb al	Dimensions	In Millimeters	Dimension	s In Inches
Symbol	Min	Max	Min	Max
А	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.150	0.350	0.006	0.014
С	0.080	0.150	0.003	0.006
D	2.000	2.200	0.079	0.087
Е	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
е	0.650	(BSC)	0.026	(BSC)
e1	1.300	(BSC)	0.051	(BSC)
L	0.260	0.460	0.010	0.018
L1	0.5	525	0.021	
θ	0°	8°	0°	8°